

www.vishay.com

Vishay Semiconductors

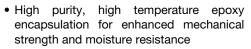
High Performance Schottky Rectifier, 16 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	16 A			
V_{R}	35 V, 45 V			
V _F at I _F	0.57 V			
I _{RM} max.	40 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	24 mJ			
Package	2L TO-220AC			
Circuit configuration	Single			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	16	А	
V _{RRM}		35, 45	V	
I _{FSM}	t _p = 5 μs sine	1800	А	
V _F	16 A _{pk} , T _J = 125 °C	0.57	V	
TJ	Range	-65 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBR1635-M3	VS-MBR1645-M3	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}	33	45	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 134 °C, rated V _R		16	Α
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1800	A
	T GIVI	Surge applied at rated load of single phase, 60 Hz	condition half wave	150	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.6 \text{A}, L = 3.7 \text{mH}$		24	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 3.6		Α	



VS-MBR1635-M3, VS-MBR1645-M3

Vishay Semiconductors

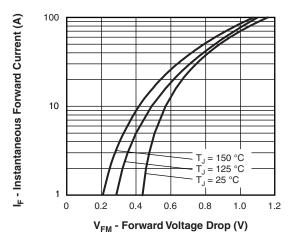
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop), (1)	V _{FM} ⁽¹⁾ 16 A	T _J = 25 °C	0.63	V
waxiinum lorward voitage drop	V FM (' '		T _J = 125 °C	0.57	
1 (1)	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA
Maximum instantaneous reverse current I _{RM} (1)		T _J = 125 °C	Haled DC Vollage	40	IIIA
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C 1400 pF		pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane 8.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/		V/µs	

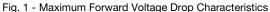
Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	TJ		-65 to +150	°C
Maximum storage temperature range	T _{Stg}		-65 to +175	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.50	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV
Approximate weight			2	g
Approximate weight			0.07	OZ.
Mauratic st Assessed			6 (5)	kgf ⋅ cm
Mounting torque — maximum			12 (10)	(lbf \cdot in)
Morting device		Coop atula 21, TO 220AC (IEDEC)	MBR1635	
Marking device		Case style 2L TO-220AC (JEDEC)	MBR1645	

Vishay Semiconductors





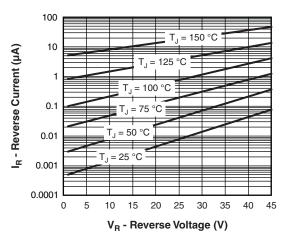


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

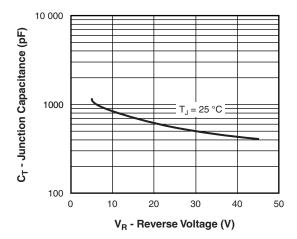


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

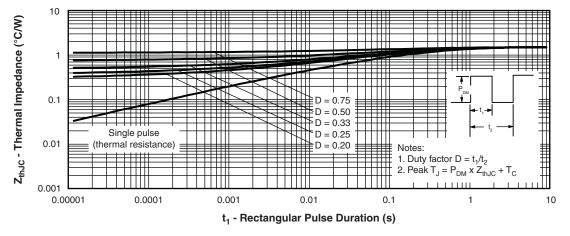


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



www.vishay.com

Vishay Semiconductors

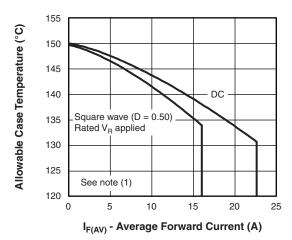


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

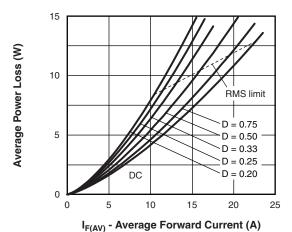


Fig. 6 - Forward Power Loss Characteristics

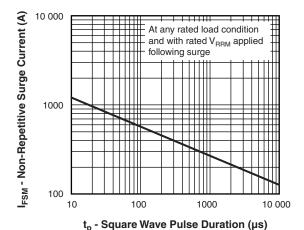


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

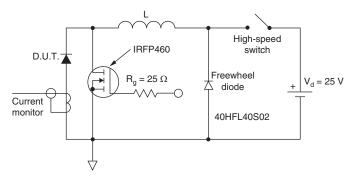


Fig. 8 - Unclamped Inductive Test Circuit

Note

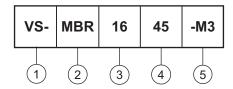
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \text{ applied} \\ \end{array}$

VS-MBR1635-M3, VS-MBR1645-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

Current rating (16 = 16 A)

- Voltage ratings — 35 = 35 V 45 = 45 V

5 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-MBR1635-M3	50	1000	Antistatic plastic tube	
VS-MBR1645-M3	50	1000	Antistatic plastic tube	

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?96156</u>			
Part marking information	www.vishay.com/doc?95391		



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.